

DOCKET NO. US010631

Examiner: Noo N

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Application No.: 10/015,640) Art Unit: 2814
Filed: 12/10/2001)
For: HIGH FREQUENCY HIGH VOLTAGE)
SILICON-ON-INSULATOR DEVICE WITH MASK VARIABLE INVERSION CHANNEL)
AND METHOD FOR FORMING THE SAME	<u>)</u>
Mail Stop AF	
Commissioner for Patents	TECHII T
P.O. Box 1450	
Alexandria, VA 22313-1450	拉 芳 斉

After-Final Amendment

Sir:

Introductory Comments

Applicants: Letavic et al.

In response to the Final Office Action of July 31, 2003, please amend the aboveidentified patent application as follows:

SN: 10/015,640